IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

PLICANT:

Nevin et al.

GROUP:

2823

SERIAL NO:

10/699,503

EXAMINER:.

Hsien Ming Lee

FILED:

10/31/03

Date of mailing

of Notice of

FOR: METHOD FOR FORMING A FILLED TRENCH Allowance:

12/30/05

IN A SEMICONDUCTOR LAYER OF A SEMICONDUCTOR SUBSTRATE, AND A SEMICONDUCTOR SUBSTRATE WITH A SEMICONDUCTOR LAYER HAVING A FILLED

TRENCH THEREIN

Mail Stop Issue Fee **Assistant Commissioner of Patents** P.O. Box 1450, Alexandria, VA 22313-1450

Attn: Official Draftsman

TRANSMITTAL OF FORMAL DRAWINGS

Applicant submits herewith new drawing(s) for this application. Attached please find eight (8) sheets of formal drawings for this application.

The three month period of response set in the Notice of Allowability (PTOL 37) expires on March 30, 2006, and this submission is on or before this expiry date.

Respectfully submitted,

Matthew E. Connors Registration No. 33,298

Gauthier & Connors

225 Franklin Street, Suite 2300

Boston, Massachusetts 02110

Telephone: (61.7) 426-9180

Extension 112

I hereby certify that this paper (along with any paper referred to as being attached or enclosed) is being deposited with the United States Postal Service on the date shown below with sufficient postage as first class mail in an envelope appearessed to the Commissioner of Patents and Trademarks, P.O. Box 1450, Alexandria, VA 22313-145 Mail Stop: Issue Fee

2-28-06